NSN 5961-01-259-0864

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-259-0864 **Inclosure Material:** Glass **Overall Length:** 0.160 inches **Terminal Length:** 1.000 inches **Overall Diameter:** 0.073 inches **Function For Which Designed:** Switching Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-35 **Mounting Method: Terminal Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 60.0 reverse voltage, peak **Current Rating Per Characteristic:** 200.00 nanoamperes forward current, average peak **Capacitance Rating In Picofarads:** 2.2 **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: